



#### Low-Voltage, 4:1 Mux/Demux with Low-Swing Control Inputs

#### **Features**

- → CMOS Technology for Analog Applications
- → Low-swing control inputs
- → Low On-Resistance
- → Wide V<sub>DD</sub> Range: 1.8V to 3.3V
- → Rail-to-Rail Signal Range
- → Near zero propagation delay
- → Fast Switching Speed
- → Ultra-low quiescent power
- → High Off Isolation: -95dB @ 100kHz
- → Crosstalk Rejection Reduces Signal Distortion: -90dB @ 100kHz
- → Packaging (Pb-free & Green): -10-contact TQFN (1.6×1.3)

#### Description

Diodes' PI3A114-A is a one-to-four bidirectional multiplier-demultiplier. Specified over a wide operating power supply voltage of 1.8 to 3.3V, the PI3A114-A offer good signal linearity.

The PI3A114-A offers low-swing input voltage on the EN, S1 and S0 inputs allowing the device to operate at 3.3V, and pass 3.3V channel data, while being controlled from a 1.8V device.

#### Block Diagram



#### Pin Configuration (top view)



#### Truth Table<sup>(1)</sup>

Enable	Sel	lect	Function			
EN	<b>S</b> <sub>1</sub>	S <sub>0</sub>	Function			
L	X	X	Y=A <sub>x</sub> , Hi-Z			
Н	L	L	$Y = A_0; A_1, A_2, A_3 = Hi-Z$			
Н	L	Н	$Y = A_1; A_{0}, A_2, A_3 = Hi-Z$			
Н	Н	L	$Y = A_2; A_0, A_1, A_3 = Hi-Z$			
Н	Н	Н	$Y = A_3; A_0, A_1, A_2 = Hi-Z$			

#### **Pin Description**

Pin Name	Description
A <sub>N</sub>	Data I/O
S <sub>0-1</sub>	Select Inputs
EN	Enable
Y	Data I/O Common
GND	Ground
V <sub>DD</sub>	Power





#### Absolute Maximum Ratings<sup>(1)</sup>

# **Recommended Operating Conditions**<sup>(3)</sup>

Supply Voltage $V_{DD}$	$\label{eq:supply Voltage Operating (V_{DD}) \dots 1.8V \text{ to } 3.3V \pm 5\% \\ \text{Control Input Voltage (V_{IN}) \dots 0V to V_{DD} \\ \text{Switch Input Voltage (V_{INPUT}) \dots -0.3V to V_{DD} \\ \text{Operating Temperature (T_A) \dots -40^{\circ}\text{C to } +85^{\circ}\text{C} \\ \end{array}$
Peak Current NO_NC_COM_ (pulsed at 1ms 50% duty cycle)±400mA Peak Current NO_NC_COM_ (mulsed at 1ms 10% (duty cycle)	Input Rise and Fall Time $(t_r, t_f)$ Control Input $V_{DD} = 2.3V - 3.6V \dots 0ns/V$ to 10ns/V Thermal Resistance $(\theta_{JA}) \dots 350^{\circ}C/W$
(pursed at Tms 10% duty cycle) $\pm$ 500mA Storage Temperature Range (T <sub>STG</sub> )65°C to +150°C Junction Temperature under Bias (T <sub>J</sub> )150°C Junction Lead Temperature (T <sub>L</sub> )	

Notes:

1. "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed. 2

3. Control input must be held HIGH or LOW; it must not float.

#### DC Electrical Characteristics +1.8V Supply

Power Dissipation (PD) @ +85°C ...... 250mW

 $(V_{DD} = 1.8V, T_A = -40^{\circ}C \text{ to } 85^{\circ}C, \text{ unless otherwise noted.})$ 

Parameter	Description	Test Conditions	Min.	<b>Typ.</b> <sup>(2)</sup>	Max.	Units
Analog Swi	tch					
Y, Ax	Analog Signal Range		-0.3		V <sub>DD</sub>	V
R <sub>ON</sub>	On-Resistance	$I_{\rm Y}$ = 100mA, $V_{\rm IN}$ = 0 to $V_{\rm DD}$			9	
$\Delta R_{ON}$	On-Resistance Match Between Channels	$I_{\rm Y} = 100 {\rm mA},  V_{\rm IN} = 0.5 {\rm V}_{\rm DD}$			0.6	Ω
R <sub>ONF</sub>	On-Resistance Flatness	$I_{\rm Y}$ = 100mA, $V_{\rm IN}$ = 0 to $V_{\rm DD}$			5	
THD	Total Harmonic Distortion	Load = 100K $\Omega$ , V <sub>IN</sub> = 0.5V <sub>DD</sub> , Frequency = 20Hz to 20KHz		0.03		%
<b>Control Inp</b>	uts <sup>(1)</sup>	•				
V <sub>IH</sub>	Input HIGH Voltage	Guaranteed Logic HIGH Level	1.5			V
V <sub>IL</sub>	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5		0.8	v
I <sub>IH</sub>	Input HIGH Current	$V_{DD} = Max., V_{IN} = V_{DD}$			±1	
I <sub>IL</sub>	Input LOW Current	$V_{DD} = Max., V_{IN} = GND$			±1	пΔ
I <sub>OZH</sub>	High Impedance Output Current	$0 \leq I_N,  Y_N \leq V_{DD}$			±1	μ
V <sub>IK</sub>	Clamp Diode Voltage	$V_{DD} = Min., I_{IN} = -18mA$			-1.2	V

Notes:

For digital control inputs EN, S0, S1. 1.

Typical values are at  $V_{DD}$  = 1.8V,  $T_A$  = 25°C ambient and maximum loading. 2.

For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type. 3.

4. Measured by the voltage drop between A and Y pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two (I,Y) pins.





#### **Power Supply Characteristics +1.8V Supply**

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	<b>Typ.</b> <sup>(2)</sup>	Max.	Units
I <sub>CC</sub>	Quiescent Power Supply Current	V <sub>DD</sub> = Max.	$V_{IN} = GND \text{ or } V_{DD}$		0.1	9.0	μΑ

Notes:

Control inputs only; A and Y pins do not contribute to I<sub>CC</sub>. 1.

Typical values are at V<sub>DD</sub> = 1.8V, T<sub>A</sub> = 25°C ambient and maximum loading. 2.

3. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.

#### DC Electrical Characteristics +3.3V Supply

 $(V_{DD} = 3.3V, T_A = -40^{\circ}C \text{ to } 85^{\circ}C, \text{ unless otherwise noted.})$ 

Parameter	Description	Test Conditions	Min.	<b>Typ</b> <sup>(2)</sup>	Max.	Units
Analog Swit	tch					
Y, Ax	Analog Signal Range		-0.3		V <sub>DD</sub>	V
R <sub>ON</sub>	On-Resistance	$I_{\rm Y}$ = 100mA, $V_{\rm IN}$ = 0 to $V_{\rm DD}$			5	
ΔR <sub>ON</sub>	On-Resistance Match Between Channels	$I_{\rm Y} = 100 {\rm mA}, V_{\rm IN} = 0.5 {\rm V}_{\rm DD}$			0.2	Ω
R <sub>ONF</sub>	On-Resistance Flatness	$I_{\rm Y}$ = 100mA, $V_{\rm IN}$ = 0 to $V_{\rm DD}$			0.6	
THD	Total Harmonic Distortion	Load = $100K\Omega$ , $V_{IN} = 0.5V_{DD}$ , Frequency = 20Hz to 20KHz		0.03		%
Control Inpu	ıts <sup>(1)</sup>					
V <sub>IH</sub>	Input HIGH Voltage	Guaranteed Logic HIGH Level	1.5			V
V <sub>IL</sub>	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5		0.8	v
I <sub>IH</sub>	Input HIGH Current	$V_{DD} = Max., V_{IN} = V_{DD}$			±1	
I <sub>IL</sub>	Input LOW Current	$V_{DD} = Max., V_{IN} = GND$			±1	
I <sub>OZH</sub>	High Impedance Output Current	$0 \leq I_N,  Y_N \leq V_{DD}$			±1	μΛ
V <sub>IK</sub>	Clamp Diode Voltage	$V_{DD} = Min., I_{IN} = -18mA$			-1.2	V

Notes:

For digital control inputs EN, S0, S1. 1.

For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device. 2.

2. Typical values are at  $V_{DD} = 3.3V$ ,  $T_A = 25^{\circ}C$  ambient and maximum loading.

Measured by the voltage drop between A and Y pin at indicated current through the switch. On-Resistance is determined by the lower of the voltages on the two 3 (I,Y) pins.

### **Power Supply Characteristics, 3.3V Supply**

Parameters	Description	Test Conditions <sup>(1)</sup>		Min.	<b>Typ.</b> <sup>(2)</sup>	Max.	Units
I <sub>CC</sub>	Quiescent Power Supply Current	$V_{DD} = Max.$	$V_{IN} = GND \text{ or } V_{DD}$		0.1	9.0	μΑ

Notes:

For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device. 1.

2 Typical values are at  $V_{DD} = 3.3V$ ,  $+25^{\circ}C$  ambient.

Control inputs only; A and Y pins do not contribute to I<sub>CC</sub>. 3.





### **Switch and AC Characteristics**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
t <sub>ON</sub>	Turn-On Time			5	15	20
t <sub>OFF</sub>	Turn-Off Time			35	50	IIS
Q	Charge Injection	$COM = 0, R_S = 0, C_L = 1nF, V_{DD} = 3.3V See Test$ Circuit Figure 4.		15		pC
O <sub>IRR</sub>	Off-Isolation	$ \begin{array}{l} C_L = 5 p F, \ R_L = 50 \Omega, \ f = 100 k Hz, \\ V_{IN} = 1 \ V_{RMS}, \ V_{DD} = 3.3 V \\ See \ Test \ Circuit \ Figure \ 5. \end{array} $		-95		-ID
X <sub>TALK</sub>	Crosstalk	$ \begin{array}{l} C_L = 5 p F, \ R_L = 50 \Omega, \ f = 100 k Hz, \\ V_{IN} = 1 \ V_{RMS}, \ V_{DD} = 3.3 V \\ See \ Test \ Circuit \ Figure \ 6. \end{array} $		-90		đВ
f <sub>3dB</sub>	3dB Bandwidth	See Test Circuit Figure 9., $V_{DD} = 3.3V$		250		MHz
$t_{pd}^{(1)}$	Propogation delay	$C_L = 5pF, R_L = 500km$			0.25	ns

Note:

1. This Parameter is not production tested.

#### Capacitance

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
C <sub>NC (OFF)</sub>	Off Capacitance	f = 1MHz, See Test Circuit Figure 7.		15		ъE
C <sub>NC (ON)</sub>	On Capacitance	f = 1MHz, See Test Circuit Figure 8.		25		рг





# **Test Circuits and Timing Diagrams**



Figure 1. AC Test Circuit

Notes:

Unused input (NC or NO) must be grounded. 1.







Figure 3. Break Before Make Interval Timing



**Figure 4. Charge Injection Test** 

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**Figure 5. Off Isolation** 



Figure 7. Channel Off Capacitance



**Figure 6. Crosstalk** 



Figure 8. Channel On Capacitance



**Figure 9. Bandwidth** 





# Packaging Mechanical: 10-pin TQFN (ZL)



13-0175

#### For latest package info.

please check: http://www.diodes.com/design/support/packaging/pericom-packaging/packaging-mechanicals-and-thermal-characteristics/

#### **Ordering Information**

<b>Ordering</b> Code	Packaging Code	Package Type	Top Mark
PI3A114-AZLEX	ZL	10-Contact, Thin Fine Pitch Quad Flat No-Lead (TQFN)	CR

Notes:

· Thermal characteristics can be found on the company web site at www.diodes.com/design/support/packaging/

• E = Pb-free and Green

• X suffix = Tape/Reel





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